# NSN 5961-01-102-2868

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-102-2868

#### **Inclosure Material:**

Metal

**Overall Length:** 

0.688 inches

### **Overall Diameter:**

0.915 inches

#### **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### Features Provided:

#### Hermetically sealed case

#### **Overall Width Across Flats:**

1.078 inches

#### Thread Size:

0.500 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

125.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

50.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

350.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

# **Special Features:**

Junction pattern arrangement: npn

# **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

1 threaded stud and 3 tab, solder lug

#### Specification Data:

81349-mil-s-19500/380 government specification

Shelf Life:

NI/o

# NSN 5961-01-102-2868

Transistor - Page 2 of 2

Unit Of Measure:

---

Demilitarization:

No

Fiig:

A110a0

